DESCRIPTION									F	REVISI	ONS	·									
REV	LTR	DESCRIPTION									DA	TE (Y	P-MO-E	DA)		APPROVED					
REV	А	Changes in accordance with NOR 5962-R140-96.										96-06-12 N					M. A. FRYE				
SHEET		Add device type 02. Add RHA requirements. Add case outlines G, H, and Changes were made to paragraphs 1.3, 1.4, table I, and table IIA. Update								d P.											
SHEET																					
SHEET	REV	1		···	· · · · · ·		_	<u> </u>	ĺ	Ι	Γ	l	!]	1		Γ	T		Τ.	
REV								<u> </u>							-	-			1		
REV B B B B B B B B B	-							<u> </u>		<u> </u>	 				····		ļ	 	 		
PMIC N/A PREPARED BY RICK OFFICER STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A PREPARED BY RICK OFFICER CHECKED BY RAJESH PITHADIA CHECKED BY RAJESH PITHADIA CHECKED BY RAJESH PITHADIA CHECKED BY RAJESH PITHADIA APPROVED BY MICHAEL FRYE MICROCIRCUIT, LINEAR, RADIATION HARDENED, LOW NOISE PRECISION, OPERATIONAL AMPLIFIER, MONOLITHIC SILICON PREVISION LEVEL B SIZE CAGE CODE A 67268 5962-94680								ļ		 										1	1
PMIC N/A PREPARED BY RICK OFFICER DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216 CHECKED BY RAJESH PITHADIA THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A PREVISION LEVEL B DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216 MICROCIRCUIT, LINEAR, RADIATION HARDENED, LOW NOISE PRECISION, OPERATIONAL AMPLIFIER, MONOLITHIC SILICON SILICON SIZE CAGE CODE A 67268 5962-94680	REV STATUS			L	REV	,		В	В	В	В	В	В	В	В	В	В	В	В	В	
STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A REVISION LEVEL B DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216 MICROCIRCUIT, LINEAR, RADIATION HARDENED, LOW NOISE PRECISION, OPERATIONAL AMPLIFIER, MONOLITHIC SILICON SIZE AGE CODE A 67268 5962-94680	OF SHEETS				SHE	ET		1	2	3	4	5	6	7	8	9	10	11	12	13	
STANDARD MICROCIRCUIT DRAWING APPROVED BY MICHAEL FRYE AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A CHECKED BY RAJESH PITHADIA COLUMBUS, OHIO 43216 MICROCIRCUIT, LINEAR, RADIATION HARDENED, LOW NOISE PRECISION, OPERATIONAL AMPLIFIER, MONOLITHIC SILICON SIZE CAGE CODE A 67268 SHEET	PMIC N/A											וח	FFFN	SE S	IIDDI	V CF	NTF	r COI	IIMP	uis.	
THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A MICHAEL FRYE MICROCIRCUIT, LINEAR, RADIATION HARDENED, LOW NOISE PRECISION, OPERATIONAL AMPLIFIER, MONOLITHIC SILICON REVISION LEVEL B SIZE CAGE CODE A 67268 5962-94680 SHEET	MICRO	CIRC	CUIT					IADIA													
AMSC N/A REVISION LEVEL B SIZE CAGE CODE A 67268 5962-94680 SHEET	FOR USE BY ALL								HA OP	RDEI ERA	VED, TION	LOW	V NO	ISE F	PREC	SISIO	N,	0			
B A 67268 5962-94680					DRA			OVAL E	DATE												
SHEET	AM	SC N/A			REVI	SION					1		1					5962	-9468	30	
1 OF 13					ŀ						SHEET 1 OF 13										

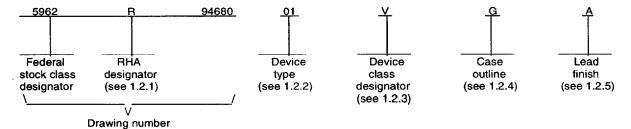
DSCC FORM 2233
APR 97
DISTRIBUTION STATEMENT A Approved for public release; distribution is unlimited.

5962-E476-98

9004708 0039304 817 📟

1. SCOPE

- 1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels are reflected in the PIN.
 - 1.2 PIN. The PIN is as shown in the following example:



- 1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
 - 1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

Device type	Generic number	Circuit function
01	OP-27B	Low noise precision operational amplifier
02	OP-27A	Low noise precision operational amplifier

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as follows:

Device class

Device requirements documentation

M

Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A

Q or V

Certification and qualification to MIL-PRF-38535

1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
G	MACY1-X8	8	Can
Н	GDFP1-F10 or CDFP2-F10	10	Flat pack
Р	GDIP1-T8 or CDIP2-T8	8	Dual-in-line
2	CQCC1-N20	20	Square leadless chip carrier

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL B	SHEET 2

DSCC FORM 2234

APR 97

9004708 0039305 756

1.3 Absolute maximum ratings. 1/

Supply voltage (V _S)Internal power dissipation	
Input voltage 2/	
Output short-circuit duration	Indefinite
Differential input voltage 3/	±0.7 V
Differential input current 3/	±25 mA
Storage temperature range	-65°C to +150°C
Operating temperature range	
Lead temperature (soldering, 60 seconds)	+300°C
Junction temperature range (T _J)	-65°C to +150°C
Thermal resistance, junction-to-case (θ _{JC})	

35

Thermal resistance, junction-to-ambient (θ_{JA}):

Case P 119°C/W Case 2 110°C/W

1.4 Recommended operating conditions.

Supply voltage (V _S)	±4.5 V to ±18 V
Source resistor (Rs)	50 Ω
Ambient operating temperature range (T _A)	-55°C to +125°C

1.5 Radiation Features:

Total Dose≤ 100 Krads

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DoDISS) and supplement thereto, cited in the solicitation.

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-973 - Configuration Management.

MIL-STD-1835 - Interface Standard For Microcircuit Case Outlines.

Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

For supply voltages less than ±22 V, the absolute maximum input voltage is equal to the supply voltages.

The device inputs are protected by back-to-back diodes. Current limiting resistors are not used in order to achieve low noise. If differential input voltage exceeds ±0.7 V, the input current should be limited to 25 mA.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		B	3

DSCC FORM 2234

APR 97

- 9004708 0039306 692 **-**

HANDBOOKS

DEPARTMENT OF DEFENSE

MIL-HDBK-103 - List of Standard Microcircuit Drawings (SMD's).

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Unless otherwise indicated, copies of the specification, standards, and handbooks are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.
 - 3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein.
 - 3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.5 Radiation exposure circuit. The radiation exposure circuit shall be as specified on figure 2.
- 3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full ambient operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.
- 3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-HDBK-103. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.
- 3.5.1 <u>Certification/compliance mark</u>. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.
- 3.6 <u>Certificate of compliance</u>. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL B	SHEET 4

DSCC FORM 2234

APR 97

9004708 0039307 529

-55°C			ns <u>1</u> / <u>2</u> / _A ≤+125°C vise specified	Group A subgroups	Device type	Limits <u>3</u> /		Unit
						Min	Max]
Input offset voltage	Vos			4	01		60	μV
				6		<u>-</u>	200	
				4	02	-25	25	1
				6		-60	60	1
	:		M,D,L,R	4		-100	100	
Average input offset voltage 4/	TCVos	$T_A = +125^{\circ}C,$	-55°C	5, 6	01		1.3	μV/°C
⊐′					02	-0.6	0.6	İ
Input offset current	los			1	01		50	nA
				2, 3			85	
				1	02	-35	+35	
				2, 3		-50	+50	
			M,D,L,R	1		-100	100	
Average input bias current	I _{IB}		<u> </u>	1	01	-55	+55	nA
		1		2, 3		-95	+95	1
				1	02	-40	+40	1
				2, 3	1	-60	+60	1
			M,D,L,R	1	1	-1000	1000	1
Input voltage range	IVR	<u>4</u> / <u>5</u> /		1	01, 02	-11	+11	V
				2,3	1	-10.3	+10.3	1

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL B	SHEET 5

DSCC FORM 2234

APR 97

9004708 0039308 465

Test	Symbol	-55°C ≤ T _A	Conditions <u>1</u> / <u>2</u> / -55°C ≤ T _A ≤+125°C unless otherwise specified		Device type	Lim	nits <u>3</u> /	Unit
· · · · · · · · · · · · · · · · · · ·	<u> </u>					Min	Max	
Power supply rejection ratio 4/	PSRR	$V_S = \pm 4 \text{ V to } \pm$	±18 V	1	01		10	μV/V
_ ,	1	$V_{S} = \pm 4.5 \text{ V to}$	±18 V	2, 3	1 '		20	1
!	1	V _S = ±4 V to ±		1	02		10	
		$V_{S} = \pm 4.5 \text{ V to}$	2 ±18 V	2, 3	1		16]
Output voltage swing 4/	Vоит	R _L ≥2 kΩ		1	01	-12	+12	V
1		R _L ≥ 600 Ω		1		-10	+10	1
1		R _L ≥ 2 kΩ		2, 3		-11	+11	1
1		R _L ≥2 kΩ		1	02	-12	+12	1
1		R _L ≥ 600 Ω		1		-10	+10	†
ı		R _L ≥ 2 kΩ		2, 3	1	-11.5	11.5	1
Supply current	1s	No load, T _A =	+25°C	1	01, 02		4.67	mA
			M,D,L,R	1	02		4.7	1
Power dissipation 4/	PD	No load, T _A =	+25°C	1	01, 02		140	mW
Offset adjustment range 4/	Vos ADJ	R _{PK} = 10 kΩ,	T _A = +25°C	1	01, 02	-0.5	+0.5	m∨
Output short-circuit current 4/	+lsc	T _A = 25°C		1	01, 02		+70	mA
<u></u>	-lsc	+				-70		1
Input noise voltage 4/6/	E _N	$f_0 = 1 \text{ Hz to } 100 \text{ Hz},$ $T_A = +25^{\circ}\text{C}$		1	01, 02		50	nV _{RMS}
Input noise current 4/6/	IN	f _o = 1 Hz to 100 Hz, T _A = +25°C		1	01, 02		40	pA _{RMS}
Slew rate 4/	SR	V _{OUT} = ±5 V, F C _L = 100 pF, measured at - +2.5 V	$T_A = +25^{\circ}C$,	4	01, 02	1.7		V/µs

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		B	6

DSCC FORM 2234 APR 97

■ 9004708 0039309 3T1 ■

TABLE I. <u>Electrical performance characteristics</u> - Continued.							
Test	Symbol	Conditions <u>1</u> / <u>2</u> / -55°C ≤ T _A ≤+125°C unless otherwise specified	Group A subgroups	Device type	Limits 3/		Unit
					Min	Max	
Gain bandwidth 4/	GBW	T _A = +25°C	4	01, 02	5.0		MHz
Common mode rejection ratio 4/	CMRR	V _{CM} = IVR = ±11 V	4	01	106		dB
		V _{CM} = IVR = ±10.3 V	5, 6	İ	100		1
		$V_{CM} = IVR = \pm 11 V$	4	02	114		1
		V _{CM} = IVR = ±10.3 V	5, 6		108		1
Large signal voltage gain	Avo	$V_{OUT} = \pm 10 \text{ V}, \text{ R}_L \ge 2 \text{ k}\Omega$	4	01	1000		V/mV
		$V_{OUT} = \pm 10 \text{ V}, R_L \ge 600 \Omega$			800		
		$V_{OUT} = \pm 10 \text{ V}, R_L \ge 2 \text{ k}\Omega$	5, 6		500		
		$V_{OUT} = \pm 10 \text{ V}, R_L \ge 2 \text{ k}\Omega$	4	02	1000		
		M,D,L,R	4	1	100		
		$V_{OUT} = \pm 10 \text{ V}, R_L \ge 600 \Omega$	4	1	800		
		$V_{OUT} = \pm 10 \text{ V}, R_L \ge 2 \text{ k}\Omega$	5, 6		600		

^{1/} Devices supplied to this drawing have been characterized through all levels M, D, L, R of irradiation. However, this device is only tested at the "R" level. Pre and Post irradiation values are identical unless otherwise specified in table I.

2/ Unless otherwise specified, $\pm V_S = \pm 15 \text{ V}$ and source resistance (R_S) = 50 Ω .

4/ This parameter is not tested post-irradiation.

5/ Input voltage range is defined as the V_{CM} range used for the CMRR test.

- 3.8 <u>Notification of change for device class M.</u> For device class M, notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-973.
- 3.9 <u>Verification and review for device class M.</u> For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Microcircuit group assignment for device class M</u>. Device class M devices covered by this drawing shall be in microcircuit group number 49 (see MIL-PRF-38535, appendix A).

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL B	SHEET 7

DSCC FORM 2234

APR 97

^{3/} The algebraic convention, whereby the most negative value is a minimum and the most positive is a maximum, is used in this table. Negative current shall be defined as conventional current flow out of a device terminal.

^{6/} This test shall be 100% tested at preburn-in of interim electrical parameters and guaranteed to the limits specified in table I herein.

Device types	02	02	01 and 02		
Case outlines	G, P	Н	2		
Terminal number		Terminal symbol			
1	BALANCE	NC	NC		
2	-INPUT	NULL	BALANCE		
3	+INPUT	-INPUT	NC		
4	-Vs	+INPUT	NC		
5	NC	-Vs	-INPUT		
6	OUT	NC	NC		
7	+Vs	OUT	+INPUT		
8	BALANCE	+Vs	NC		
9		NULL	NC		
10		NC	-Vs		
11			NC		
12			NC		
13			NC		
14			NC		
15			OUT		
16			NC		
17			+Vs		
18			NC		
19			NC		
20		l	BALANCE		

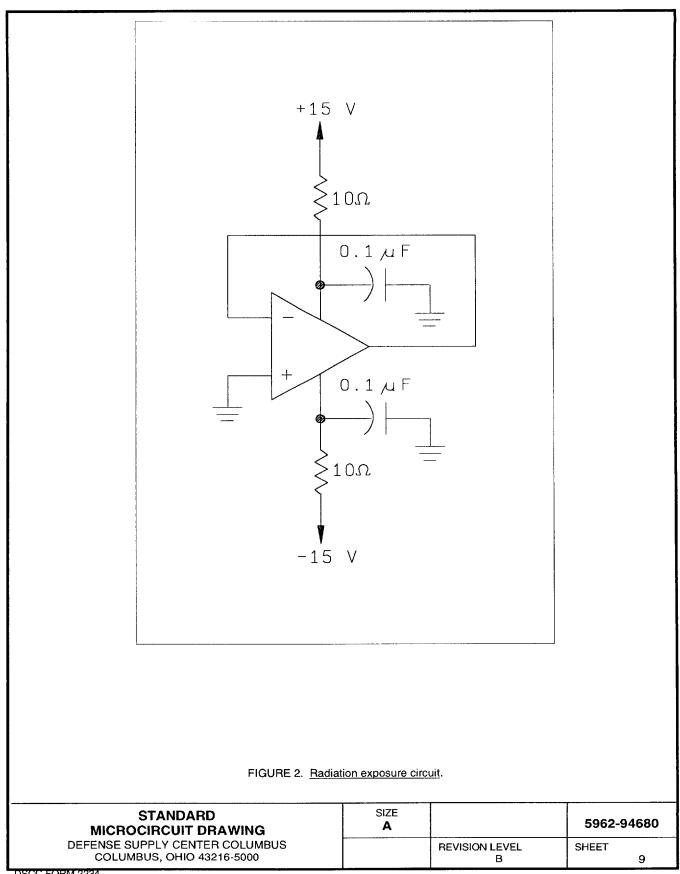
NC = No connection

FIGURE 1. Terminal connections.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL B	SHEET 8

DSCC FORM 2234 APR 97

■ 9004708 0039311 T5T ■



DSCC FORM 2234 APR 97

■ 9004708 0039312 996 **■**

4. QUALITY ASSURANCE PROVISIONS

- 4.1 <u>Sampling and inspection</u>. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.
- 4.2 <u>Screening</u>. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.
 - 4.2.1 Additional criteria for device class M.
 - a. Bum-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table IIA herein.
 - 4.2.2 Additional criteria for device classes Q and V.
 - a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - b. Interim and final electrical test parameters shall be as specified in table IIA herein.
 - Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.
- 4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).
- 4.4 <u>Conformance inspection</u>. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-PRF-38535 permits alternate in-line control testing. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL B	SHEET 10

DSCC FORM 2234

APR 97

9004708 0039313 822

TABLE IIA. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class M	Device class Q	Device class V
Interim electrical parameters (see 4.2)	1	1	1
Final electrical parameters (see 4.2)	1,2,3,4 <u>1</u> /	1,2,3,4 <u>1</u> /	1,2,3,4 <u>1</u> /
Group A test requirements (see 4.4)	1,2,3,4,5,6	1,2,3,4,5,6	1,2,3,4,5,6
Group C end-point electrical parameters (see 4.4)	1	1	1 <u>2</u> /
Group D end-point electrical parameters (see 4.4)	1	1	1
Group E end-point electrical parameters (see 4.4)			1, 4

^{1/} PDA applies to subgroup 1.

Table IIB. 240 hour burn-in and group C end-point electrical parameters.

Parameter	Device type	Limit		Delta
		Min	Max	
Vio	02	-135	+135	±75 μV
I _{IB}	02	-70	+70	±10 nA

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Subgroups 7, 8, 9, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
- 4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.
- 4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:
 - a. Test condition A, B, C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
 - b. $T_A = +125^{\circ}C$, minimum.
 - c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL B	SHEET 11

DSCC FORM 2234

APR 97

9004708 0039314 769 📟

^{2/} See table IIB for delta measurement parameters.

- 4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
 - 4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.
- 4.4.4 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes M, Q, and V shall be as specified in MIL-PRF-38535. End-point electrical parameters shall be as specified in table IIA herein.
- 4.4.4.1 <u>Total dose irradiation testing</u>. Total dose irradiation testing shall be performed in accordance with MIL-STD-883 method 1019 and as specified herein.
- 4.4.4.1.1 <u>Accelerated aging test</u>. Accelerated aging tests shall be performed on all devices requiring a RHA level greater than 5k rads(Si). The post-anneal end-point electrical parameter limits shall be as specified in table I herein and shall be the pre-irradiation end-point electrical parameter limit at 25 C ±5 C. Testing shall be performed at initial qualification and after any design or process changes which may affect the RHA response of the device.
- 4.4.4.2 <u>Dose rate burnout</u>. When required by the customer test shall be performed on devices, SEC, or approved test structures at technology qualifications and after any design or process changes which may effect the RHA capability of the process. Dose rate burnout shall be performed in accordance with test method 1023 of MIL-STD-883 and as specified herein.

5. PACKAGING

5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

6. NOTES

- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.1.1 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.
 - $\textbf{6.1.2} \ \ \underline{\textbf{Substitutability}}. \ \ \textbf{Device class Q devices will replace device class M devices}.$
- 6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.
- 6.3 Record of users. Military and industrial users should inform Defense Supply Center Columbus when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0525.
- 6.4 Comments. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43216-5000, or telephone (614) 692-0674.
- 6.5 <u>Abbreviations, symbols, and definitions</u>. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		B	12

DSCC FORM 2234

APR 97

9004708 0039315 6T5 🖿

6.6 Sources of supply.					
6.6.1 <u>Sources of supply for device classes Q and V</u> . Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.					
6.6.2 <u>Approved sources of supply for device class M</u> . Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.					
			'		
			'		
	0175	T			
STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94680		
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL B	SHEET 13		
DSCC FORM 2234 APR 97			10		

■ 9004708 0039316 531 ■

STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 98-09-02

Approved sources of supply for SMD 5962-94680 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535.

Standard microcircuit drawing PIN 1/	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-9468001M2A	24355	OP27BRC/883C
5962R9468002VGA	24355	OP27AJ/QMLR
5962R9468002VPA	24355	OP27AZ/QMLR
5962R9468002V2A	24355	OP27ARC/QMLR
5962R9468002VHA	24355	OP27AL/QMLR

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

24355

Vendor name and address

Analog Devices RT 1 Industrial Park PO Box 9106 Norwood, MA 02062

Point of contact: 1500 Space Park Drive

PO Box 58020

Santa Clara, CA 95052-8020

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.

9004708 0039317 478

110709